CMOS LSI

LC89610



## Preliminary

SANYO

#### Overview

The LC89610 is a playback signal processing CMOS LSI that supports the mini-disk data format. Data that has been decoded by a CD decoder, an ACIRC decoder, or a CD-ROM decoder circuit is passed to a DRAM controller circuit and the LC89610 uses external DRAM to process shock proof. The shock proof processed data is passed to an audio data decoding LSI, the LC89602.

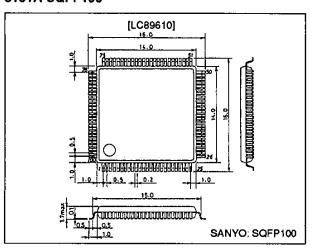
No. 💥 5120

#### Features

- · EFM decoder and PLL clock generator
- Detection, protection, and interpolation of the EFM frame synchronization signal
- Servo command control
- On-chip ACIRC decoder and ACIRC RAM
- ±8 frame jitter margin
- Powerful error detection and correction (C1: dual errors, C2: quadruple errors)
- · CLV control using EFM and ADIP signals
- · Subcode Q decoding and CRC error checking
- Shock proof memory using 1, 4, 16, or 64 Mbits of external DRAM
- Buffering control and management for TOC and UTOC data
- · Buffering control and management for subdata
- · ADIP decoding and CRC error checking
- Low-power design using a 0.8 μm rule CMOS process
- Support for low-voltage operation ( $V_{DD} = 3.0$  to 5.5 V)
- CCB based CPU interface

# **Package Dimensions**

unit: mm 3181A-SQFP100



### SANYO Electric Co., Ltd. Semiconductor Business Headquarters TOKYO OFFICE Tokyo Bldg., 1-10, 1 Chome, Ueno, Taito-ku, TOKYO, 110 JAPAN

## **Specifications**

### Absolute Maximum Ratings at $V_{SS}$ = 0 V

Parameter	Symbol	Conditions	Ratings	Unit
Maximum supply voltage	V <sub>DD</sub> max	Ta = 25°C	-0.3 to +7.0	V
Input and output voltages	v <sub>i</sub> v <sub>o</sub>	Ta = 25°C	-0.3 to V <sub>DD</sub> + 0.3	V
Operating temperature	Topr		-30 to +70	°C
Storage temperature	Tstg		55 to +125	°C
Soldering conditions		10 seconds (pins only)	260	•C

#### Allowable Operating Ranges at Ta = -30 to $+70^{\circ}$ C, $V_{SS} = 0$ V

Parameter	Symbol	Conditions	min	typ	max	Unit
Supply voltage	V <sub>DD</sub>		3.0		5.5	V
Input voltage	V <sub>IN</sub>		0		V <sub>DD</sub>	V

# DC Characteristics at Ta = -30 to +70 $^{\circ}C$ , $V_{SS}$ = 0 V, $V_{DD}$ = 4.5 to 5.5 V

Parameter	Symbol	Conditions	min	typ	max	Unit
Input high level voltage	VIH	*1	0.8 V <sub>DD</sub>	-		v
Input low level voltage	VIL	*1			0.2 V <sub>DD</sub>	v
Input high level voltage	VIH	*2	0.7 V <sub>DD</sub>			v
Input low level voltage	VIL	*2			0.3 V <sub>DD</sub>	v
Input high level voltage	VIH	*3	0.6 V <sub>DD</sub>			v
Input low level voltage	VIL	*3			0.4 V <sub>DD</sub>	v
Output high level voltage	V <sub>OH</sub>	I <sub>OH</sub> = -1 mA, *4	V <sub>DD</sub> - 0.1			v
Output low level voltage	V <sub>OL</sub>	l <sub>OL</sub> ⊨ 1 mA, *4			0.1	v
Output high level voltage	V <sub>OH</sub>	I <sub>OH</sub> = -1 mA, *5	V <sub>DD</sub> - 1.0		······································	v
Output low level voltage	V <sub>OL</sub>	l <sub>OL</sub> = 1 mA, *5			1.0	v
Output high level voltage	V <sub>OH</sub>	I <sub>OH</sub> = -3 mA, *6	V <sub>DD</sub> - 2.1			v
Output low level voltage	VOL	t <sub>OL</sub> = 3 mA, *7			0.4	v
Input leakage current	և	$V_1 = V_{SS}, V_{DD}$	-10		+10	μA
Output leakage current	loz	For high-impedance state outputs	-10		+10	۸ µ
Pull-up resistance	R <sub>UP</sub>	*8	10	20	40	kΩ
Quiescent current	IDD	*9		0.1	200	μA
Oulescent current		*10		250	475	μA

Note: 1. HFL, TES, CE, CL, SUBREQ, SREQ, RESET, ADIPCRI, BIDATAI, BICLKI 2. Inputs other than \*1, 2, and 4 XIN. 3. EFMIN

4. PDO

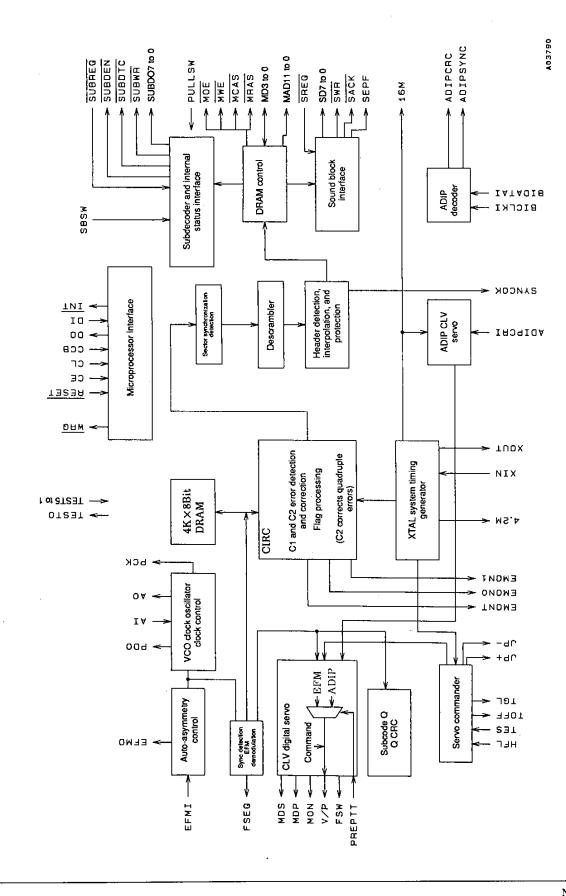
5. EFMO

6. Outputs other than \*5 and \*6 XOUT, AO, and DO (open-drain output).

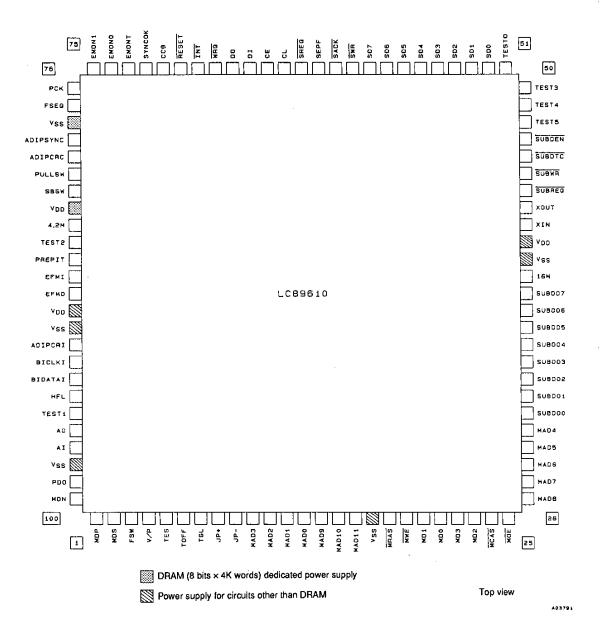
7. Outputs other than \*5 and \*6 XOUT, and AO.

8. For MD0 to MD3, TEST1 to TEST5. However, note that the pull-up resistors are not connected when the PULLSW pin is low.

9. When the PULLSW pin is low, outputs are open, and V<sub>I</sub> = V<sub>SS</sub> or V<sub>DD</sub>. 10.When the PULLSW pin is high, outputs are open, and V<sub>I</sub> = V<sub>SS</sub> or V<sub>DD</sub>.



**Block Diagram** 



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#### **Pin Functions**

Pin No.	Symbol	1/0	Function
1	MDP	0	CLV servo signal output
2	MDS	0	CLV servo signal output
3	FSW	0	CLV servo signal output
4	V/P	0	CLV servo signal output
5	TES	ł	Track jump signal input
6	TOFF	0	Track jump signal output
7	TGL	0	Track jump signal output
8	JP +	0	Track jump signal output
9	JP –	0	Track jump signal output
10	MAD3	0	DRAM address output
11	MAD2	0	DRAM address output
12	MAD1	0	DRAM address output
13	MADO	0	DRAM address output
14	MAD9	- 0	DRAM address output
15	MAD10	0	DRAM address output
16	MAD11	0	DRAM address output
17	V <sub>SS</sub>	-	Ground
18	MRAS	0	DRAM RAS signal output
19	MILLES	0	DRAM WE signal output
20	MD1	1/0	DRAM data VO
20	MD1	1/0	DRAM data VO
21	MD3	1/0	DRAM data VO
22	MD3	1/0	DRAM data VO
	MCAS		DRAM CAS signal output
24 25	MOAS	0	· · · ·
		0	DRAM OE signal output
26	MAD8	0	DRAM address output
27	MAD7	0	DRAM address output
28	MAD6	0	DRAM address output
29	MAD5	0	DRAM address output
30	MAD4	0	DRAM address output
31	SUBDO0	0	Subdata and internal status output
32	SUBDO1	0	Subdata and internal status output
33	SUBDO2	0	Subdata and internal status output
34	SUBDO3	0	Subdata and internal status output
35	SUBDO4	0	Subdata and internal status output
36	SUBDO5	0	Subdata and internal status output
37	SUBDO6	0	Subdata and internal status output
38	SUBDO7	0	Subdata and internal status output
39	16M	0	16.9344 MHz clock output
40	V <sub>SS</sub>		V <sub>SS</sub> ground
41	V <sub>DD</sub>	—	Power supply
42	XIN	1	16.9344 oscillator input
43	XOUT	0	16.9344 oscillator output
44	SUBREO	1	Subdata request signal input
45	SUBWR	0	Subdata transfer clock output
46	SUBDTC	0	Subdata transfer complete signal output
47	SUBDEN	0	Subdata enable output
48	TEST5	1	Test input (normally tied to V <sub>DD</sub> )
49	TEST4	1	Test input (normally tied to V <sub>DD</sub> )
50	TEST3	1	Test input (normally tied to V <sub>DD</sub> )
51	TESTO	1	Test output
52	SD0	0	Sound block data output
53	SD1	Ó	Sound block data output
54	SD2	0	Sound block data output

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Ріл No,	Symbol	l vo	Function
56	SD4	0	Sound block data output
57	SD5		Sound block data output
58	SD6	0	Sound block data output
59	SD7	0	Sound block data output
60	SWR	0	Sound block data transfer clock output
61	SACK	0	Sound block data acknowledge signal output
62	SEPF	0	Sound block data empty signal output
63	SREQ		Sound block data request signal input
64	CL	1	CPU interface data transfer clock input
65	CE	1	CPU interface chip enable signal input
66	DI	1	CPU Interface data input
67	DO	0	CPU interface data output
68	WRQ	0	CPU interface interrupt signal output
69	INT	0	CPU interface interrupt signal output
70	RESET	1	System reset
71	ССВ	1	CPU interface type switching input
72	SYNCOK	0	Sector synchronization detection signal output
73	EMONT	0	Error detection monitor signal output
74	EMON0	0	Error detection monitor signal output
75	EMON1	0	Error detection monitor signal output
76	PCK	0	4.3218 MHz monitor signal output
77	FSEQ	0	Frame synchronization detection signal output
78	V <sub>SS</sub>	_	Ground (for the on-chip DRAM only)
79	ADIPSYN	0	ADIP synchronization timing signal output
80	ADIPCRC	0	ADIP data CRC flag output
81	PULLSW	1 1	Internal pull-up resistor switching signal input
82	SBSW		Subdata/internal status switching signal input
83	V <sub>DD</sub>	-	Power supply (for the on-chip DRAM only)
84	4.2M		Test input (normally tied to V <sub>DD</sub> )
85	TEST2	1	Test input (normally tied to V <sub>DD</sub> )
86	PREPIT	1	CLV servo output signal switching input
87	EFMI	1	HF signal input
88	EFMO	0	EFM signal output
89	V <sub>DD</sub>	-	Power supply
90	V <sub>SS</sub>		Ground
91	ADIPCRI		ADIP carrier signal input
92	BICLK	1	Bi-phase data transfer clock input
93	BIDATAI		Bi-phase data input
94	HFL	Ĩ	Track detection signal input
95	TEST1	0	4.2336 MHz output
96	AO	0	VCO control signal output
97	AI		VCO control signal input
98	V <sub>SS</sub>	0	VCO control signal output
99	PDO	—	Ground
100	MON	0	CLV servo signal output

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